

ISOTOP[®] Buck chopper NPT IGBT

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$V_{CES} = 600V$ $I_{C} = 100A$ @ Tc = 80°C

Application

- AC and DC motor control
- Switched Mode Power Supplies

Features

- Non Punch Through (NPT) THUNDERBOLT IGBT
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 100 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- ISOTOP[®] Package (SOT-227)
- Very low stray inductance
- High level of integration

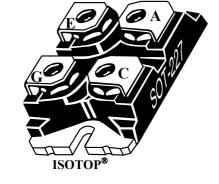
Benefits

- Outstanding performance at high frequency operation
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive T_C of V_{CEsat}
- RoHS Compliant

Absolute maximum ratings

| Symbol | Parameter | | | Max ratings | Unit |
|-------------------|---|---------------------|---------------------|-------------|------|
| V _{CES} | Collector - Emitter Breakdown Voltage | | | 600 | V |
| I _{C1} | Continuous Collector Current $T_C = 2$ | | | 120 | |
| I _{C2} | Continuous Conector Current | $T_C = 80^{\circ}C$ | 100 | Α | |
| I _{CM} | Pulsed Collector Current $T_c = 2$ | | | 320 | |
| V _{GE} | Gate – Emitter Voltage | | | ±20 | V |
| P _D | Maximum Power Dissipation | | $T_C = 25^{\circ}C$ | 416 | W |
| IF _{AV} | Maximum Average Forward Current | Duty cycle=0.5 | $T_C = 80^{\circ}C$ | 30 | А |
| IF _{RMS} | RMS Forward Current (Square wave, 50% duty) | | | 39 | Л |

These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.



APT100GF60JU3- Rev 2 October, 2012



All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

Electrical Characteristics

| Symbol | Characteristic | Test Conditions | | Min | Тур | Max | Unit |
|----------------------|--------------------------------------|---|----------------------|-----|-----|------|------|
| I _{CES} | Zero Gate Voltage Collector Current | | | | 100 | μA | |
| | | | $T_j = 125^{\circ}C$ | | | 1000 | μΑ |
| V _{CE(sat)} | Collector Emitter saturation Voltage | $V_{GE} = 15V$ | $T_j = 25^{\circ}C$ | | 2.0 | 2.5 | V |
| | | $I_{\rm C} = 100 {\rm A}$ $T_{\rm j} = 125^{\circ} {\rm C}$ | | 2.2 | | v | |
| V _{GE(th)} | Gate Threshold Voltage | $V_{GE} = V_{CE}, I_C = 1 \text{mA}$ | | 3 | | 5 | V |
| I _{GES} | Gate – Emitter Leakage Current | $V_{GE} = \pm 20V, V_{CE} = 0V$ | | | | ±150 | nA |

Dynamic Characteristics

| Symbol | Characteristic | Test Conditions | Min | Тур | Max | Unit |
|---------------------|------------------------------|--|-----|------|-----|------|
| Cies | Input Capacitance | $V_{GE} = 0V$ | | 4300 | | |
| C _{oes} | Output Capacitance | $V_{CE} = 25V$ | | 470 | | pF |
| C _{res} | Reverse Transfer Capacitance | f = 1 MHz | | 400 | | |
| Q_{g} | Total gate Charge | $V_{GS} = 15V$ | | 330 | | |
| Q _{ge} | Gate – Emitter Charge | $V_{Bus} = 300V$ | | 290 | | nC |
| Q _{gc} | Gate – Collector Charge | $I_{\rm C} = 100 {\rm A}$ | | 200 | | |
| T _{d(on)} | Turn-on Delay Time | Resistive Switching (25°C) | | 26 | | |
| T _r | Rise Time | $V_{GE} = 15V$ $V_{GE} = 400V$ | | 25 | | ns |
| T _{d(off)} | Turn-off Delay Time | $V_{Bus} = 400V$ $I_{C} = 100A$ | | 150 | | |
| T _f | Fall Time | $R_G = 5\Omega$ | | 30 | | |
| Eon | Turn-on Switching Energy | | | 3.35 | | mI |
| E _{off} | Turn off Switching Energy | | | 2.85 | | mJ |
| T _{d(on)} | Turn-on Delay Time | Inductive Switching (125°C) $V_{GE} = 15V$ $V_{Bus} = 400V$ $I_C = 100A$ $R_G = 5\Omega$ | | 26 | | |
| Tr | Rise Time | | | 25 | | |
| T _{d(off)} | Turn-off Delay Time | | | 170 | | ns |
| T_{f} | Fall Time | | | 40 | | |
| Eon | Turn-on Switching Energy | | | 4.3 | | mJ |
| E _{off} | Turn-off Switching Energy | | | 3.5 | | IIIJ |



Chopper diode ratings and characteristics

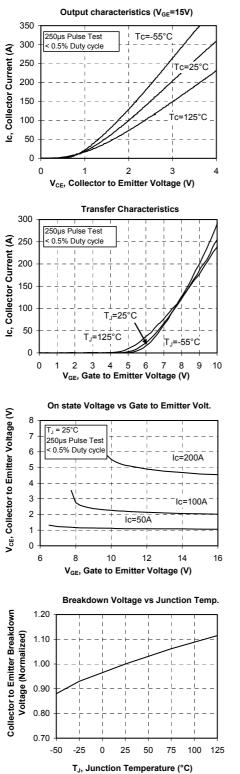
| Symbol | Characteristic | Test Conditions | | Min | Тур | Max | Unit |
|------------------|----------------------------------|--|------------------------|-----|------|-----|------|
| $V_{\rm F}$ | Diode Forward Voltage | $I_F = 30A$ | | | 1.6 | 1.8 | |
| | | $I_F = 60A$ | | | 1.9 | | V |
| | | $I_F = 30A$ | $T_{i} = 125^{\circ}C$ | | 1.4 | | |
| I _{RM} | Maximum Reverse Leakage Current | $V_{R} = 600 V$ | $T_j = 25^{\circ}C$ | | | 250 | μA |
| IRM | Waximum Reverse Leakage Current | $V_{R} = 600 V$ | $T_{j} = 125^{\circ}C$ | | | 500 | - |
| C _T | Junction Capacitance | $V_{R} = 200V$ | | | 44 | | pF |
| 4 | Reverse Recovery Time | $I_F=1A, V_R=30V$ di/dt =100A/µs | $T_j = 25^{\circ}C$ | | 23 | | |
| t _{rr} | Reverse Recovery Time | $T_{i} = 25^{\circ}C$ $T_{i} = 125^{\circ}C$ $T_{i} = 25^{\circ}C$ $T_{i} = 25^{\circ}C$ | $T_i = 25^{\circ}C$ | | 85 | | ns |
| | | | | 160 | | | |
| I _{RRM} | Maximum Reverse Recovery Current | | $T_j = 25^{\circ}C$ | | 4 | | А |
| IRRM | Waximum Reverse Recovery Current | $V_{\rm R} = 400 V$ | $T_{i} = 125^{\circ}C$ | | 8 | | А |
| 0 | Deverse Deservery Charge | - di/dt =200A/µs | $T_j = 25^{\circ}C$ | | 130 | | nC |
| Q _{rr} | Reverse Recovery Charge | | $T_{j} = 125^{\circ}C$ | | 700 | | IIC |
| t _{rr} | Reverse Recovery Time | $I_F = 30A$ $V_R = 400V$ $di/dt = 1000A/\mu s$ | | | 70 | | ns |
| Q _{rr} | Reverse Recovery Charge | | $T_j = 125^{\circ}C$ | | 1300 | | nC |
| I _{RRM} | Maximum Reverse Recovery Current | | | | 30 | | А |

Thermal and package characteristics

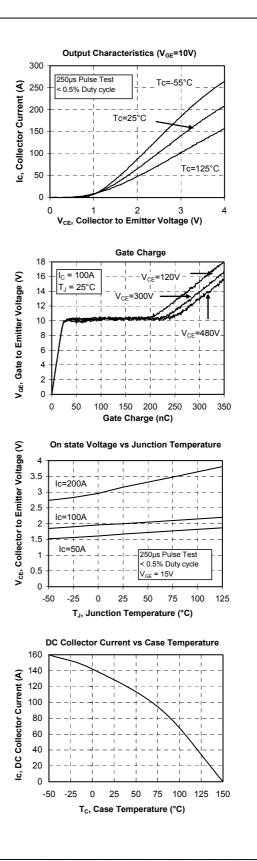
| Symbol | Characteristic | | Min | Тур | Max | Unit | |
|-------------------|--|-------|------|------|------|------|--|
| R _{thJC} | Junction to Case Thermal Resistance | IGBT | | | 0.3 | °C/W | |
| | | Diode | | | 1.21 | | |
| R _{thJA} | Junction to Ambient (IGBT & Diode) | | | | 20 | | |
| V _{ISOL} | RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz | | 2500 | | | V | |
| T_J, T_{STG} | Storage Temperature Range | | -55 | | 150 | °C | |
| T _L | Max Lead Temp for Soldering:0.063" from case for 10 sec | | | | 300 | - C | |
| Torque | Mounting torque (Mounting = 8-32 or 4mm Machine and terminals = 4mm Machine) | | | | 1.5 | N.m | |
| Wt | Package Weight | | | 29.2 | | g | |



Typical IGBT Performance Curve



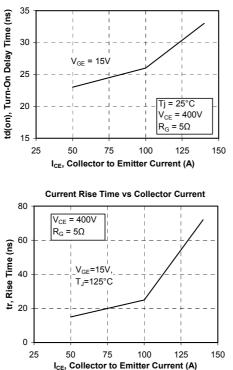
APT100GF60JU3



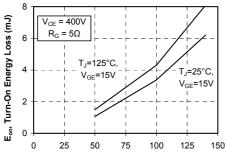
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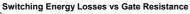
Turn-On Delay Time vs Collector Current

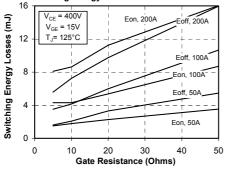




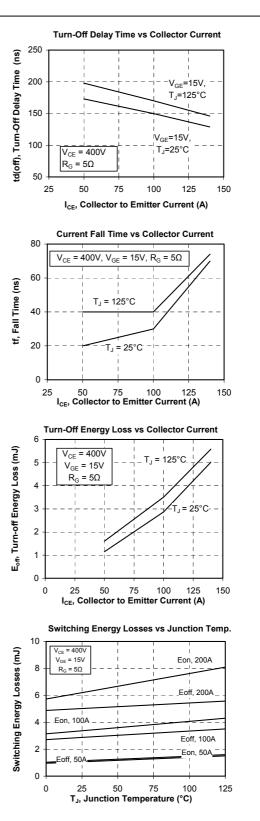


I_{CE}, Collector to Emitter Current (A)



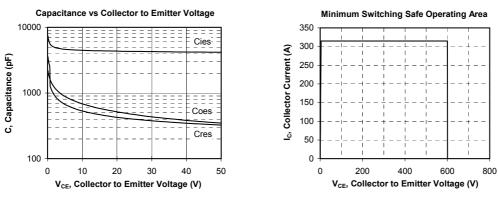


APT100GF60JU3

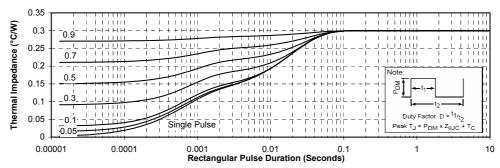


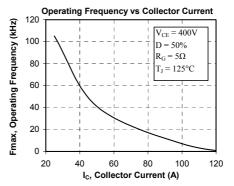
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Maximum Effective Transient Thermal Impedance, Junction to Case vs Pulse Duration







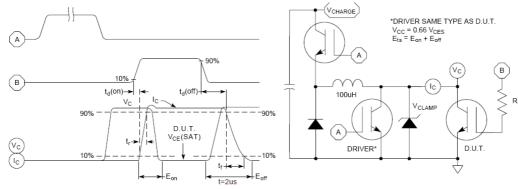


Figure 15, Switching Loss Test Circuit and Waveforms

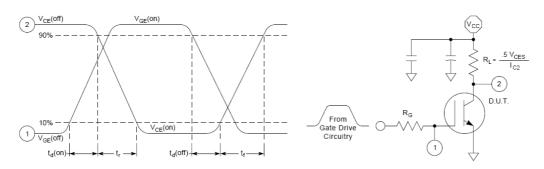
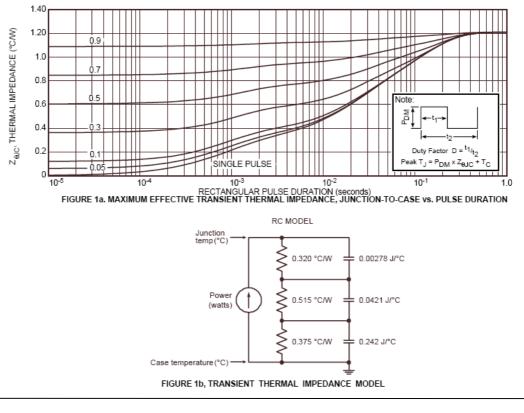
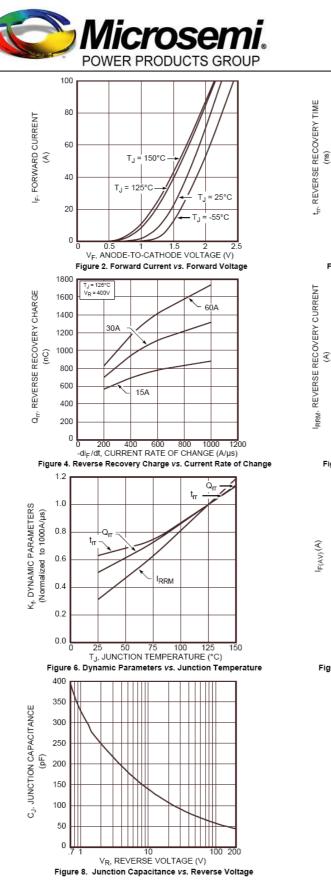


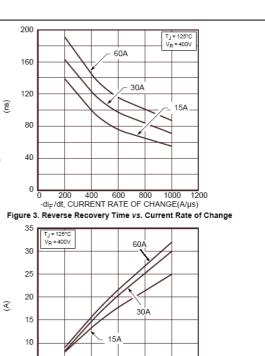
Figure 16, Resistive Switching Time Test Circuit and Waveforms

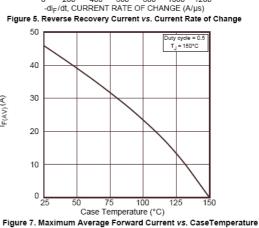


Typical Diode Performance Curve

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400 600

5

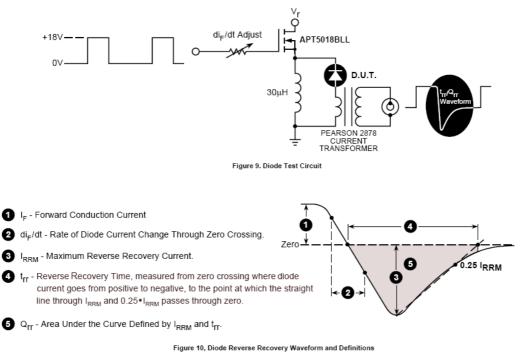
0

0 200

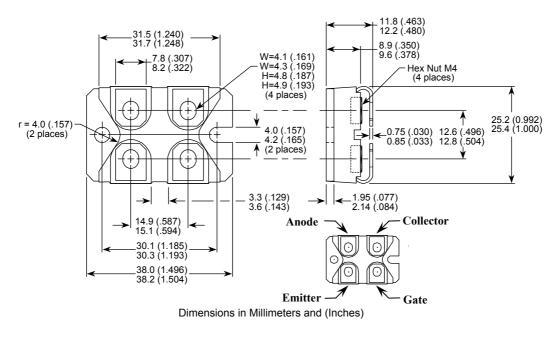
800

1000 1200





SOT-227 (ISOTOP[®]) Package Outline



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